# MMBV609LT1G

# **Silicon Tuning Diode**

This device is designed for FM tuning, general frequency control and tuning, or any top-of-the-line application requiring back-to-back diode configuration for minimum signal distortion and detuning. This device is supplied in the SOT-23 plastic package for high volume, pick and place assembly requirements.

#### **Features**

- High Figure of Merit Q = 450 (Typ) @  $V_R = 3.0$  Vdc, f = 50 MHz
- Guaranteed Capacitance Range
- Dual Diodes Save Space and Reduce Cost
- Surface Mount Package
- Available in 8 mm Tape and Reel
- Monolithic Chip Provides Improved Matching
- Hyper Abrupt Junction Process Provides High Tuning Ratio
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS** (EACH DIODE)

| ,  |                  |             |             |  |  |
|--|------------------|-------------|-------------|--|--|
| Rating   | Symbol           | Value       | Unit        |  |  |
| Reverse Voltage  | V <sub>R</sub>   | 20          | Vdc         |  |  |
| Forward Current  | I <sub>F</sub>   | 100         | mAdc        |  |  |
| Total Power Dissipation @ T <sub>A</sub> = 25°C<br>Derate above 25°C | P <sub>D</sub>   | 225<br>1.8  | mW<br>mW/°C |  |  |
| Junction Temperature   | TJ               | +125        | °C          |  |  |
| Storage Temperature Range  | T <sub>stg</sub> | -55 to +125 | °C          |  |  |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



# ON Semiconductor®

http://onsemi.com

# DUAL VOLTAGE VARIABLE CAPACITANCE DIODE





SOT-23 (TO-236) CASE 318 STYLE 9

## **MARKING DIAGRAM**



5L = Specific Device Code

M = Date Code\*

■ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

### **ORDERING INFORMATION**

| Device      | Package             | Shipping <sup>†</sup> |
|-------------|---------------------|-----------------------|
| MMBV609LT1G | SOT-23<br>(Pb-Free) | 3,000 / Tape & Reel   |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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# **ELECTRICAL CHARACTERISTICS** (EACH DIODE) (T<sub>A</sub> = 25°C unless otherwise noted)

| Characteristic   | Symbol             | Min | Тур | Max | Unit |
|--|--------------------|-----|-----|-----|------|
| Reverse Breakdown Voltage ( $I_R = 10 \mu Adc$ )             | V <sub>(BR)R</sub> | 20  | -   | -   | Vdc  |
| Reverse Voltage Leakage Current (V <sub>R</sub> = 15 Vdc)    | I <sub>R</sub>     | -   | -   | 10  | nAdc |
| Diode Capacitance<br>(V <sub>R</sub> = 3.0 Vdc, f = 1.0 MHz) | C <sub>T</sub>     | 26  | -   | 32  | pF   |
| Capacitance Ratio C3/C8<br>(f = 1.0 MHz)                     | C <sub>R</sub>     | 1.8 | -   | 2.4 | -    |
| Figure of Merit<br>(V <sub>R</sub> = 3.0 Vdc, f = 50 MHz)    | Q                  | 250 | 450 | -   | -    |

# **TYPICAL CHARACTERISTICS**

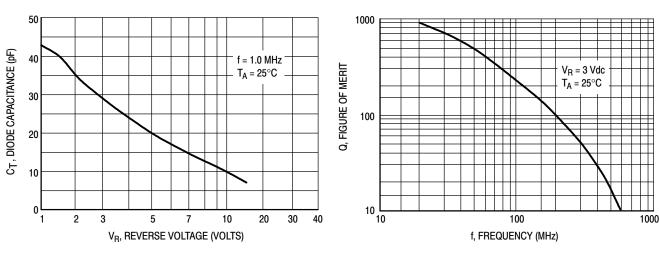


Figure 1. Diode Capacitance

Figure 2. Figure of Merit

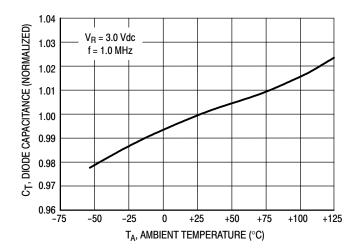
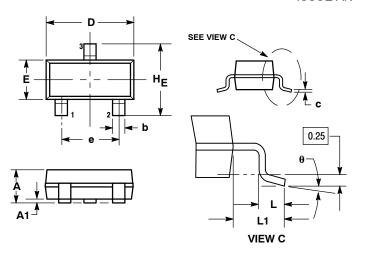


Figure 3. Diode Capacitance

#### MMBV609LT1G

## PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN** 



#### NOTES

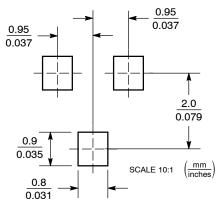
- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD
- THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

|     | MILLIMETERS |      |      | INCHES |       |       |
|-----|-------------|------|------|--------|-------|-------|
| DIM | MIN         | NOM  | MAX  | MIN    | NOM   | MAX   |
| Α   | 0.89        | 1.00 | 1.11 | 0.035  | 0.040 | 0.044 |
| A1  | 0.01        | 0.06 | 0.10 | 0.001  | 0.002 | 0.004 |
| р   | 0.37        | 0.44 | 0.50 | 0.015  | 0.018 | 0.020 |
| 0   | 0.09        | 0.13 | 0.18 | 0.003  | 0.005 | 0.007 |
| D   | 2.80        | 2.90 | 3.04 | 0.110  | 0.114 | 0.120 |
| Е   | 1.20        | 1.30 | 1.40 | 0.047  | 0.051 | 0.055 |
| е   | 1.78        | 1.90 | 2.04 | 0.070  | 0.075 | 0.081 |
| ٦   | 0.10        | 0.20 | 0.30 | 0.004  | 0.008 | 0.012 |
| L1  | 0.35        | 0.54 | 0.69 | 0.014  | 0.021 | 0.029 |
| HE  | 2.10        | 2.40 | 2.64 | 0.083  | 0.094 | 0.104 |

#### STYLE 9:

- PIN 1. ANODE
  - 2. ANODE
  - CATHODE

# **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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